Mapping of strained graphene into one-dimensional Hamiltonians: Quasicrystals and modulated crystals

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The electronic properties of graphene under any arbitrary uniaxial strain field are obtained by an exact mapping of the corresponding tight-binding Hamiltonian into an effective one-dimensional modulated chain. For a periodic modulation, the system displays a rich behavior, including quasicrystals and modulated crystals with a complex spectrum, including gaps and peaks at the Fermi energy and localization transitions. All these features are explained by the incommensurate or commensurate nature of the potential, which leads to a dense filling by diffraction spots of the reciprocal space in the former case. The essential features of strain are made specially clear by analyzing a special momenta that uncouples the model into dimers.

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Graphene is a two-dimensional (2D) carbon crystal [1]. This atom-thin elastic membrane has amazing physical properties [1–4]. Notably, graphene has the highest known interval of elastic response (up to 20% of the lattice parameter [5]). The tailoring of its electronic properties by controlled mechanic deformation is a field known as “straintronics” [6–9]. Also, graphene seems to be the ideal candidate to replace Si in transistors. However, when graphene grows in top of a substrate with different lattice parameters or structure, strain and corrugation appear [10]. The understanding of how strain affects the graphene’s electronic properties is clearly a fundamental issue, still in the process of development [11–17]. How strain affects the electronic spectrum and wave functions? By mapping the limiting case of any uniaxial strain to an effective one-dimensional Hamiltonian, we prove that the answer is unexpectedly rich. As we will see, in certain circumstances strain promotes a quasiperiodic fractal electronic behavior due to the complex self-similar structure of the reciprocal space. Furthermore, it is known that a fractal answer is unexpectedly rich. As we will see, in certain circumstances strain promotes a quasiperiodic fractal electronic behavior due to the complex self-similar structure of the reciprocal space. Furthermore, it is known that a fractal behavior can be obtained in rotated bilayer graphene under magnetic fields [18–21]. Here we prove that a similar effect can be obtained in single-layer graphene. Such effect should be generated by growing graphene in top of a crystal with a slightly different lattice parameter, as is now technically feasible [20]. As is known, this leads to a periodic strain [10]. Then a quasiperiodic behavior should be obtained when the ratio of lattice parameters becomes incommensurate. Other two-dimensional materials like MoS$_2$ or NiSe$_2$ are expected to present the same effect [22–24].

Let us start with a zigzag graphene nanoribbon, as shown in Fig. 1, with a uniaxial strain applied in the $y$ direction. Although our methodology can be applied for uniaxial strain in the zigzag or arm chair directions, here we will concentrate only in one kind, since we want to bring out the essential features of the model.

The new positions of the carbon atoms are $r' = r + u(y)$, where $r = (x, y)$ are the unstrained coordinates of the atoms and $u(y) = (0, u(y))$ is the corresponding displacement. The electronic properties of graphene are well described by a one orbital next-nearest neighbor tight-binding Hamiltonian in a honeycomb lattice, given by [4]

$$H = -\sum_{r,n} t_{r,n} c_{r}^\dagger c_{r+n} + H.c.,$$

where $r'$ runs over all sites of the deformed lattice and $\delta_n'$ are the corresponding vectors that point to the three next nearest neighbors of $r'$. For unstrained graphene, $\delta_n' = \delta_n$, where

$$\delta_1 = \frac{a}{2}(\sqrt{3}, 1), \quad \delta_2 = \frac{a}{2}(-\sqrt{3}, 1), \quad \delta_3 = a(0, -1).$$

The operators $c_{r}$ and $c_{r+n}$ correspond to creating and annihilating electrons on lattice sites. The hopping integral $t_{r,n}$ depends upon strain, which induces bond length changes that increase or decrease the overlap between wave functions. Such variation with the distance can be calculated from [25,26] $t_{r,n} = t_0 \exp[-\beta |\delta_n'||(a - 1)|]$, where $\beta \approx 3, t_0 \approx 2.7eV$ corresponds to nonstrained pristine graphene, and $a$ is the bond length, which will be taken as $a = 1$ in what follows.

For strain in one direction, we can map exactly the Hamiltonian into an effective one dimensional system as the nanoribbon is made from cells of four nonequivalent atoms [27] with coordinates $r = (x, y^{(m)})$, where $s = 1, 2, 3, 4$ and $m$ denotes the number of the cell, as sketched out in Fig. 1. For graphene without strain, the positions in the zigzag path in the vertical direction, as indicated in Fig. 1. Taking into account that for each bond that cross the dotted lines in Fig. 1, we need to add a phase $\exp(\pm ik_x \sqrt{3}/2)$ for the wave function, it is easy
the cell, four kinds of inequivalent sites appear (shown in different colors) of the unitary cell in the \( k \) direction is sketched out using a wavy curve, while the boundaries \( \pi/3 \) in the chain. For the special momenta \( k_0 = \pi/\sqrt{3} \), the model breaks down into dimers, represented by bold links in the chain.

to obtain the following Schrödinger equation,

\[
\begin{align*}
E \psi_1(m) &= c(k_0) \psi_1^{(m)}(m) + t_4^{(m-1)} \psi_4(m-1), \\
E \psi_2(m) &= t_2^{(m)} \psi_3(m) + c(k_0) \psi_1^{(m)}(m), \\
E \psi_3(m) &= c(k_0) \psi_3^{(m)}(m) + t_2^{(m)} \psi_2(m), \\
E \psi_4(m) &= t_4^{(m)} \psi_3^{(m)}(m) + c(k_0) \psi_4^{(m)}(m),
\end{align*}
\]

(3)

where \( c(k_0) = 2 \cos(\sqrt{3}k_0/2) \) and \( t_j^{(m)} = t_0 \exp[-\beta(u_j^{(m)} - u_j^{(m-1)})] \). Here, \( \delta_{y_1+1, y_1} \) denotes the \( y \) components of each of the three vectors \( \delta_1, \delta_2, \delta_3 \) that join sites with \( y \) coordinates \( y_1^{(m)} \) and \( y_1^{(m-1)} \) for unstrained graphene. In this formula, one needs to apply the conditions \( y_5^{(m)} = y_1^{(m+1)} \) and \( y_0^{(m)} = y_4^{(m-1)} \) at the boundary of each cell. Furthermore, the sequence of \( y_j^{(m)} \) can be written as \( y(j) = [3j + 1 - (-1)^j]/2] / 4 \), where \( j \) is an integer that labels the site number along the zigzag path in the \( y \) axis, given by \( j = 4(m - 1) + s \). Finally, one can write a Hamiltonian \( H(k_0) \) without any reference to cells of four sites,

\[
H(k_0) = \sum_j \left[ t_2 c_2 j c_2 j + c(k_0) t_2 j c_2 j + c_2 j c_2 j + c_2 j c_2 j \right]
\]

(4)

with \( t_0 \delta^{(m-1)+s} = t_j^{(m)} \). This gives

\[
t_j = t_0 \exp \left[ -\beta \frac{3 + (-1)^j + 1}{4} (u_j + 1 - u_j) \right].
\]

(5)

where it is understood that \( u_j \) is just the displacement of the \( j \)th atom along the vertical zigzag path, i.e., \( u_j = u_j^{(m)} \). Now \( H(k_0) \) describes a chain for any arbitrary uniaxial strain, as indicated in Fig. 1.

The exact mapping can serve as a test for approximate theories of strain in graphene. Consider, for example, an oscillating strain \( \eta(y) = (2/3)\lambda / \beta \) \( \cos(8\pi y / 3) \lambda (y - 1/2) + \phi \) of the type expected when graphene grows on top of a material with a different lattice [10].

Figure 2 shows the complex spectrum of \( H \) as a function of \( \sigma \), revealing a behavior that is akin to the Hofstadter butterfly that appears in the Harper model [28]. The most surprising result is the appearance of gaps around the Fermi level \( E = 0 \) for some values of \( \sigma \). We can get a better understanding by using a linear approximation for \( t_{r,s} \), assuming a small strain as usual in straintronics. Under such approximation, Eq. (5) becomes

\[
t_j / t_0 = 1 + \lambda \xi (j + 1) \sin(\pi \sigma \xi (j)) \sin(2\pi \sigma j + \phi),
\]

(6)

where \( \xi (j) = 1 + [(1)^j / 3] \).

The resulting Hamiltonian describes one-dimensional quasiparticles for irrational \( \sigma \), and modulated crystals for rational \( \sigma \). Although the model resembles an off-diagonal Harper model [29], there is an important extra modulation provided by \( \xi (j + 1) \sin(\pi \sigma \xi (j)) \). In Fig. 3, we present the resulting bands as a function of \( k_0 \) and the corresponding density of states (DOS) for \( \sigma = 0 \) (pure graphene), \( 3\tau / 4 \), and \( 3 / 4 \), where \( \tau \) is the golden ratio \( \tau = (\sqrt{5} - 1) / 2 \). Several interesting features are observed. The first is the disappearance of the Dirac cone for cases (c) and (e), observed around \( E = 0 \) for pure graphene. In case (c), degenerate states appear at \( E = 0 \) and the DOS is spiky. On the other hand, in case (f) the DOS is smooth. Only the Van Hove singularities observed for \( E = \pm 1 \) in pure graphene move and split in two. It is also interesting the behavior of the spectrum as a function of \( \lambda \) for a given \( \sigma \). In Figs. 4(a) and 4(b), we present the cases \( \sigma = 3\tau / 4 \) and \( \sigma = 3 / 4 \). For \( \sigma = 3 / 4 \), a gap opens above a certain critical
An analysis of Fig. 3(e) suggests that for $\sigma = 3/4$, the behavior is akin to a system of two disconnected chains. Such analysis is confirmed by evaluating Eq. (5) using $\sigma = 3/4$. In this particular case, the strain has the same period as the four site cells, thus $t_4^{(m)}$ turns out to be independent of $m$, and $t_4^{(m)} = 1 - 4\lambda/3\sin(3\pi s/2)$. The corresponding band edges are given by a matrix of $4 \times 4$ solutions, in terms of the parameters $\lambda$ and $k_x$, are $E(\lambda, k_x) = \pm [\sqrt{1 + (8\lambda/9)^4\cos^2(\sqrt{3}/2)k_x^2} \pm 2\cos(\sqrt{3}/2)k_x^2]/2$. A gap opens when $\lambda = \lambda_C = \sqrt{3}/8$. However, for irrational $\sigma$, the factor $\sin(4\pi \sigma l + \phi)$ behaves as a pseudorandom number generator which fills in a dense way the interval $[0,1)$. The degeneracy is thus lifted. The spectral type is pure point and contained in the interval $[0,1]$, with its eigenvalues being integers.

For the value $k_x = \pi/\sqrt{3}$, we have that $c(k_x) = 0$. This is valid for any $\lambda$ or $\sigma$. The corresponding Hamiltonian $H(k_x = \pi/\sqrt{3})$ given by Eq. (4) becomes just a model for disconnected dimers, represented in the chain of Fig. 1 as bold lines. The eigenvalues are obtained from an effective $2 \times 2$ matrix, from where $E(k_x = \pi/\sqrt{3}) = \pm l$, with $l$ an integer. Using Eq. (6), the eigenvalues are $E(k_x = \pi/\sqrt{3}) = \pm [1 + (2/3)\lambda\sin(4\pi \sigma /3)\sin(4\pi l + \phi)]$. In the case of unstrained graphene, $E(k_x = \pi/\sqrt{3}) = \pm 1$. These two values correspond to the highly degenerate peaks observed in the DOS of Fig. 3(b). Each peak has a degeneracy $N/2$, where $N$ is the number of atoms in the zigzag path. These peaks are associated with a Van Hove singularity, since standing waves due to diffraction appear [31–33]. For $\sigma = 3/4$, $E(k_x = \pi/\sqrt{3}) = \pm 1$. The degeneracy remains, as seen in Fig. 3(e), although it does not produce peaks because all other states are also highly degenerate. However, for irrational $\sigma$, the factor $\sin(4\pi \sigma l + \phi)$ behaves as a pseudorandom number generator which fills in a dense way the interval $[0,1)$. The degeneracy is thus lifted. The spectral type is pure point and contained in the intervals $[-1 - 2\lambda/3, -1 + 2\lambda/3]$ and $[1 - 2\lambda/3, 1 + 2\lambda/3]$, leading to a gap of size $4\lambda/3$ if $\lambda < 3/2$. The splitting is evident at the middle of $k_x$ axis in Fig. 3(c), and when compared with Figs. 3(a) and 3(e). What happens to the wave-function localization? For irrational $\sigma$, the eigenfunctions are localized in dimers on the $y$ direction. Obviously, since all $E(k_x = \pi/\sqrt{3})$ are different, an infinite number of reciprocal vectors are needed to generate the corresponding wave functions. Thus, even in this simple case the usual perturbation theory breaks down. However, for rational $\sigma$, the eigenvalues are degenerate. Any linear combination of the wave function in dimers is a solution, leading to delocalized states around $k_x = \pi/\sqrt{3}$. Such behavior is revealed by calculating the normalized participation ratio, defined as [34]

$$\alpha(E) = \frac{1}{\ln N} \sum_{j=1}^N |\psi(j)|^4.$$  

The factor $\alpha(E)$ is a measure of localization. In Figs. 2 and 4, the colors indicate the value of $\alpha(E)$. For Fig. 2, a fractal behavior reveals how localization depends on the number theory properties of $\sigma$. In Fig. 4(b), the case $\sigma = 3/4$ does not present appreciable changes, as expected from the previous discussion. Only at $\lambda = \lambda_M$ there is a localization transition as a consequence of the breaking into disconnected chains, leading to the vertical red line observed in Fig. 4(b). The case $\sigma = 3\pi/4$ shows the expected localization around $E = \pm 1$ as $\lambda \to \infty$. Finally, it is worthwhile mentioning how some of the observed effects are related with the zigzag states reported.
in graphene nanoribbons [35–37] and topological states [38]. In particular, the DOS in the irrational case resembles the case of narrow graphene nanoribbons [35]. The reason for this is simple. For irrational \( \sigma \), there are sites \( j \) in which \( t_j \approx 0 \), since \( t_j \) mimics a random number generator. In such sites, the lattice is almost decoupled in the \( y \) direction, producing many effective nanoribbons of different widths. This leads to singularities that are strikingly similar to narrow nanoribbons, as observed in Fig. 3(d). In fact, a similar phenomena happens for rational \( \sigma \) and big \( \lambda \). For example, if \( \sigma = 3/4 \) and \( \lambda = \lambda_D \), \( t_j \) is zero at the end of the unitary one dimensional cell and we obtain many effective nanoribbons, but this time all with the same four atom width. In a similar way, the states at the Fermi energy can be explained in many different way: as zigzag states [35] due to an effective decoupling in nanoribbons, as an imbalance in the number of atoms in each bipartite lattice [33] or as strictly confined states [33]. These states have a topological nature, as we have verified by changing \( \phi \) and using different boundary conditions.

In conclusion, we have provided an exact mapping into a one dimensional chain for any uniaxial strain in graphene. For a periodic strain, effective quasiperiodic or modulated crystals systems were obtained. Due to the dense nature of the reciprocal space, the spectrum and localization properties presented a fractal pattern. Gaps, singularities, and localized states were observed. These features can not be predicted by simple perturbation theory techniques. The quasiperiodic nature of the problem found here, suggests the paramount importance of disorder due to the intrinsic instability of such spectra [39–42] and the possibility of building equivalent superlattices [43]. In future work, we will study edge states, since they are expected to present a nesting of topological length scales, given by the Chern numbers, within a fractal pattern, as observed in the Harper and Fibonacci models [38].

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